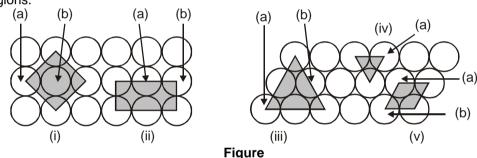


- A-1. Classify each of the following solids.
 (a) Tetra phosphorus decoxide (P₄O₁₀)
 (c) Brass
 - (e) SiC
 - (g) I2
 - (i) P₄
 - (k) Plastic.

- (b) Graphite
 (d) Ammonium phosphate [(NH₄)₃ PO₄]
 (f) Rb
 (h) LiBr
 (j) Si
- A-2. Given below are two dimension lattices with nicely shaded regions.You just have to find the contributions (in fractions) of particles marked to the shaded regions and the total number of particles in the regions.

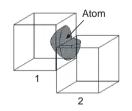


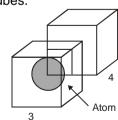
A-3. What are the crystallographic parameter of hexagonal, monoclinic and triclinic unit cell respectively.

Section (B) : Simple Cubic Structure & BCC

Commit to memory : Density = $\frac{Z \times M}{N_A \times a^3}$

B-1. Following diagrams show identical cubes such that edge of cube2 lies exactly in the middle of one of the faces of Cube1 and Cube 4 has a corner at the body center of the Cube3. Find the contributions(in fraction) of the spheres shown to each of the cubes.





- **B-2.** The inter metallic compound Li Ag crystallizes in a cubic lattice in which both lithium and silver atoms have coordination no. of 8. To what crystal class does the unit cell belong?
- **B-3.** Chromium metal crystallizes with a body centered cubic lattice. The length of the unit cell is found to be 287 pm. Calculate the atomic radius. What would be the density of chromium in g/cm³.

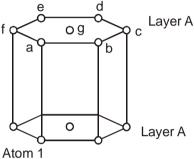
Section (C) : HCP & CCP structures

Commit to memory :

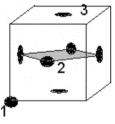
For CCP : $a = b = c = 2\sqrt{2} R$, Z = 4, Coordination number = 12

For HCP : a = 2R, b = 2R, c = 2h and h = $\sqrt{\frac{8}{3}}$ R, Z = 6, Coordination number = 12

- **C-1.** In which type of 3D arrangement have Ist and IV layer's of sphere are identical.
- **C-2.** Metallic magensium has a hexagoanl close-packed structure and a density of 1.74 g/cm³. Assume magnesium atoms to be spheres of radius r. 74.1% of the space is occupied by atoms. Calculate the volume of each atom and the atomic radius r. (Mg = 24.31)
- **C-3.** Consider a corner atom of Ist layer of an HCP unit cell showing alternate AA layers. Find (i) Find identical atoms (III layer) with respect to the distances from the atom 1.
 - (ii) Arrange the distances in ascending order.



- C-4. Following figure shows an FCC unit cell with atoms of radius r marked 1(corner), 2(face center), 3(face center). A quadrilateral is also shown by joining the centers of 4 face centered atoms.
 - Find : (i) The distances between atoms 1 & 2, 2 & 3 and 1 & 3.
 - (ii) The shape and dimensions of the quadrilateral.



Figure

- **C-5.** Aluminium metal (atomic weight = 27 g) crystallises in the cubic system with edge length 4.0Å. The density of metal is 27/16 amu/ Å³. Determine the unit cell type and calculate the radius of the Aluminium metal.
- **C-6.** "Tom" cat arranges the glass balls, in a particular 3D array; that two (I and II) continuous layer are not identical, but all (I and III) alternative layers are identical, this type of arrangement is known as :

Section (D) : Voids

Commit to memory :					
	Radius ratio = 0.155, 0.225, 0.414, 0.732 for triangular, tetrahedral, octahedral, cubic void respectively.				
D-1.	A student wants to arrange 4 identical spheres (of radius R) on a two dimensional floor as close as				

- **D-1.** A student wants to arrange 4 identical spheres (of radius R) on a two dimensional floor as close as possible. Finally he could arrange them. Identify the type and dimensions of the figure obtained by joining their centers. Could he occupy the whole available space, if not, then what type of voids were generated. Calculate their number and radius of small ball that can be fitted in them.
- D-2. Illustrate an octahedral void in the close packing of spheres. Why is it so called ?
- D-3. The number of tetrahedral and octahedral voids in hexagonal primitive unit cell are _____ and

D-4. What is the number and closest distance between two octahedral voids and two tetrahedral voids in fcc unit cell ?

Section (E) : Radius ratio rule and Type of ionic structures

Commit to memory :

Radius ratio = 0.155, 0.225, 0.414, 0.732 for triangular, tetrahedral, octahedral, cubic void respectively.

E-1. Suggest the probable structues of the unit cells of following each compound with the help of given data

		Cationic radius	Anionic radius
(a)	RbBr	1.48 Å	1.95 Å
(b)	MeTe	0.65 Å	2.21 Å
(c)	MgO	0.65 Å	1.40 Å
(d)	BaO	1.35 Å	1.40 Å

E-2. Why does ZnS not crystallize in the NaCl structure?

E-3. Try to answer the following:

(i) In Zinc Blende structure there is one Zn^{+2} ion per S^{2-} ion.But the radius ratio lies in the range of Tetrahedral void and there are two tetrahedral voids available per S^{2-} .Can you give the idea about the arrangement of the lattice.

(ii) What is the striking difference between the Fluorite and the Anti-fluorite structures.

- - (a) How many K⁺ ions and how many Br⁻ ions are in each unit cell?
 - (b) Assuming the additivity of ionic radii, what is a ?
 - (c) Calculate the density of a perfect KBr crystal.
 - (d) What minimum value of r_+/r_- is needed to prevent anion-anion contact in this structure.

Section (F) : Crystal defects and Properties of solids

Commit to memory :

Stoichiometric - The formula of compound remains same even after presence of these defects. **Non-stoichiometric** - The formula of compound will get modified because of the presence of these defects.

% missing units =

$$\frac{\rho_{\text{th}} - \rho_{\text{exp}}}{2}$$
 × 100% (Schottky Defects)

Locations of electrons in metal excess defect are also known as color centres (F-centres).

- **F-1.** What do you understand by imperfections in ionic crystals ? Name the types of imperfections which generally occur in ionic crystals.
- F-2. How would you explain that (i) non-stoichiometric NaCl is yellow ; (ii) non-stoichiometric ZnO is yellow ?
- F-3. Account the following: Silicon is an insulator but silicon doped with phosphorus acts as a semiconductor.
- F-4. How does the conductivity of a semiconductor change if its temperature is raised?

PART - II : ONLY ONE OPTION CORRECT TYPE

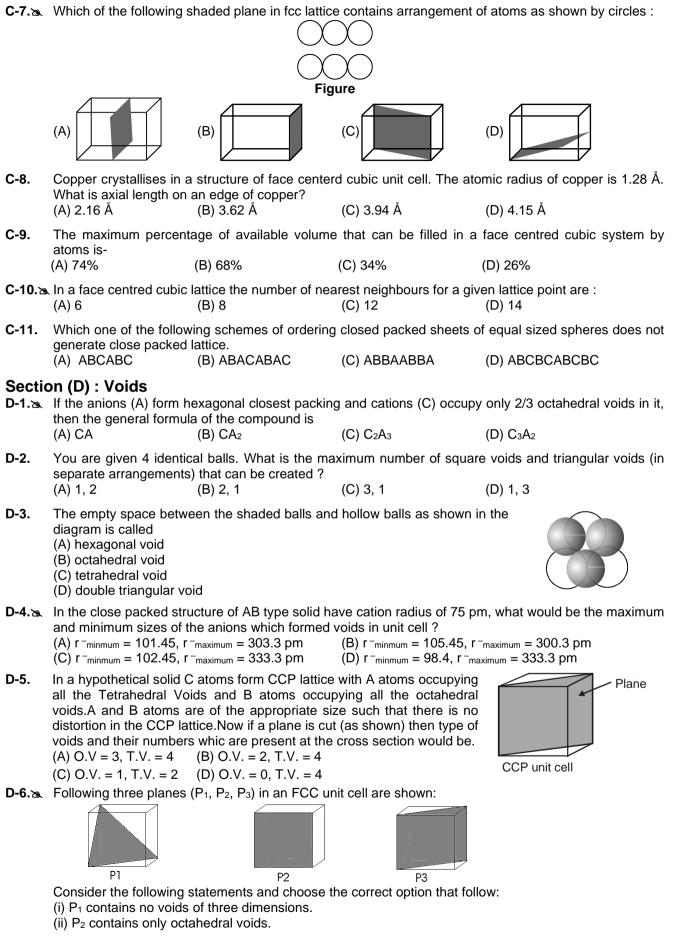
Section (A) : Basics of solid state

A-1.	Which of the follo	wing is/are pseudo solid	IS ?			
	I. KCI		II. Barium chlorid	le dihydrate		
	III. Rubber		IV. Solid cake let	IV. Solid cake left after distillation of coal tar		
	(A) I,III	(B) II, III	(C) III, IV	(D) only III		
A-2.	The smallest rep substance is calle		nen repeated in three di	mensions results in the crystal		

	(A) Space lattice	(B) Crystal lattice	(C) Unit cell	(D) coordination number
A-3.	The crystal system for	or which $a \neq b \neq c$ and $a \neq b \neq c$	$\alpha = \beta = \gamma = 90^{\circ}$ is said to	be :
	(A) triclinic	(B) tetragonal	(C) cubic	(D) orthorhombic

of the

	State			
A-4.æ	Which of the following a (A) $a = b = c$, $\alpha = \beta = \gamma$ (C) $a \neq b \neq c$, $\alpha = \beta = \gamma$	≠ 90 ⁰	ance and axial angles for (B) $a = b \neq c$, $\alpha = \beta = \gamma$ (D) $a \neq b \neq c$, $\alpha \neq \beta \neq \gamma$	= 90°
A-5.	(B) equivalent points in(C) There are four Bray	unit cells of a periodic la		
A-6.æ	The crystal system of a and $\alpha = \beta = 90^{\circ}$ and $\gamma = (A)$ Cubic		l dimensions, a = 0.387 (C) Orthorhombic	and $b = 0.387$ and $c = 0.504$ nm (D) Rhombohedral
Section	on (B) · Simple Cub	oic Structure & BCC		
B-1.		ice has co–ordination nu (B) 12		(D) 4
B-2.	What is the radius of a	n iron atom?		unit cell is found to be 286 pm.
	(A) r = 124 pm	(B) r = 128 pm	(C) $r = 124 \text{ Å}$	(D) r = 128 Å
B-3.		a body centered cubic wo nearest neighbour is	c lattice (bcc) with the e	edge of the unit cell 5.2Å. The
	(A) 10.4 Å	(B) 4.5 Å	(C) 5.2Å	(D) 9.0Å
B-4.১	theoretical density of P	o. (Atomic wt of Po = 207	7g)	ge length is 3.0 Å, calculate the
	(A) 25/3 amu/ Å ³	(B) 23/3 amu/ Å ³	(C) 21/3 amu/ Å ³	(D) 27/3 amu/ Å ³
B-5.	Lithium crystallizes in a have?	a body centered cubic la	attice. How many next-i	nearest neighbors does each Li
	(A) 6	(B) 8	(C) 12	(D) 4
B-6.১	successive atoms loca cell.Their order is given	ted along the edge, the by:		d _{bd} be the distances between diagonal respectively in a unit (D) d _{bd} > d _e > d _{fd} ,
	(A) $d_e < d_{fd} < d_{bd}$	(B) $d_{fd} > d_{bd} > d_{e}$	(C) $U_{fd} > U_e > U_{bd}$	(D) Ubd > Ue > Ufd,
Section C-1.	on (C) : HCP & CCF How many number of a (A) Exactly 6	<pre>structures toms are completely insi (B) > 6</pre>	ide the HCP unit cell ? (C) < 6	(D) 12
C-2.a	The shortest distance b	between I st and V th layer	of HCP arrangement is :	
	(A) $8\sqrt{\frac{2}{3}}$ r	(B) $4\sqrt{\frac{3}{2}}$ r	(C) $16\frac{\sqrt{2}}{3}r$	(D) $8\sqrt{\frac{3}{2}}$ r
C-3.১	Volume of HCP unit ce (A) $24\sqrt{2}$ r ³	ll is : (B) 8 √2 r³	(C) 16 √2 r ³	(D) 24 √3 r³
0 4				(D) 24 43 1
C-4.	(A) 0.74	e in ABAB type arrangen (B) 0.26	(C) 0.68	(D) 0.32
C-5.	What is the hight of an	_	_	-
	(A) $\frac{\sqrt{3}}{2}$ a	(B) $\sqrt{\frac{3}{2}}$ a	(C) $\sqrt{\frac{2}{3}} \times 2a$	(D) $\frac{\sqrt{2}}{3}$ a
	\//hatio the number of	atoms in a unit cell of fac	e-centred cubic crystal?	



- (iii) P₃ contains both octahedral and tetrahedral voids.
- (A) All are true
- (C) (i) & (iii) are true

- (B) Only (i) & (ii) are true (D) Only (iii) is true.
- D-7. In an FCC unit cell a cube is formed by joining the centers of all the tetrahedral voids to generate a new cube. Then the new cube would contain voids as : (A) 1 full tetrahedral void, 1 full octahedral void (B) 1 full tetrahedral void only (C) 8 full tetrahedral voids and 1 full octahedral void (D) 1 full Octahedral void only Section (E) : Radius ratio rule and Type of ionic structures E-1. The radius of Ag⁺ ion is 126 pm and that of I⁻ ion is 216 pm. The co-ordination number of Ag⁺ ion is. (A) 2 (B) 4 (C) 6 (D) 8 E-2. The tetrahedral voids formed by ccp arrangement of Cl⁻ ions in rock salt structure are (A) Occupied by Na⁺ ions (B) Occupied by Cl[−] ions (C) Occupied by either Na⁺ or Cl⁻ ions (D) Vacant Antifluorite structure is derived from fluorite structure by : E-3.a (A) heating fluorite crystal lattice (B) subjecting fluorite structure to high pressure (C) Inter changing the positions of positive and negative ions in the lattice (D) none of these In zinc blende structure the coordination number of Zn²⁺ ion is (A) 2 (B) 4 (C) 6 (D) 8 Strontium chloride has a fluorite structure, which of the following statement is true for the structure of strontium chloride ? (A) the strontium ions are in a body-centered cubic arrangement (B) the strontium ions are in a face-centered cubic arrangement (C) each chloride ion is at the center of a cube of 8 strontium ions (D) each strontium ion is at the center of a tetrahedron of 4 chloride ions The spinal structure (AB₂O₄) consists of an fcc array of O²⁻ ions in which the : E-6. (A) A cation occupies one-eighth of the tetrahedral holes and B cation occupies one-half of octahedral holes (B) A cation occupies one-fourth of the tetrahedral holes and the B cations the octahedral holes (C) A cation occupies one-eighth of the octahedral hole and the B cation the tetrahedral holes (D) A cation occupies one-fourth of the octahedral holes and the B cations the tetrahedral holes In the crystal lattice of diamond, carbon atoms adopt : (A) fcc arrangement along with occupancy of 50% tetrahedral holes (B) fcc arrangement along with occupancy of 25% tetrahedral holes (C) fcc arrangement along with occupancy of 25% octahedral hole (D) bcc arrangement Cesium chloride on heating to 760 K changes into (A) CsCl(g) (B) NaCI structure (C) antifluorite structure (D) ZnS structure In a solid lattice the cation has left a lattice site and is located at an interstitial position, the lattice defect is (A) Interstitial defect (B) Valency defect (C) Frenkel defect (D) Schottky defect F-2. Which of the following statements are correct in context of point defects in a crystal ? (A) AgCI has anion Frenkel defect and CaF₂ has Schottky defects (B) AgCI has cation Frenkel defects and CaF₂ has anion Frenkel defects (C) AgCI as well as CaF₂ have anion Frenkel defects (D) AgCl as well as CaF₂ has Schottky defects

- E-4.a
- E-5.

E-7.

E-8.

Section (F) : Crystal defects and Properties of solids

F-1.

F-3. A F-centers are

- (A) the electrons trapped in anionic vacancies
- (B) the electrons trapped in cation vacancies
- (C) non-equivalent sites of stoichiometric compound
- (D) all of the above
- **F-4.** Which of the following is true about the charge acquired by p-type semiconductors?
 - (A) positive(C) negative

- (B) neutral(D) depends on concentration of p impurity

PART - III : MATCH THE COLUMN

1. We are good at matching things let us try our hand on the following columns:

Solid	Constituent particle	Binding force
(a) Diamond	(e) Ion	(i) Metallic
(b) Sodium Chloride	(f) Atom	(j) Dipole dipole
(c) HCI	(g) Kernel	(k) Ionic
(d) Aluminium	(h) Molecule	(I) Covalent

2. Match the column :

	Column I (Arrangement of the atoms/ions)		Column II (Planes in fcc lattice)
(A)		(p)	
(B)	36	(q)	
(C)		(r)	
(D)	000	(s)	

3. Match the column :

	Column-I		Column-II
(A)	ZnS crystal	(p)	fcc
(B)	CaF ₂ crystal	(q)	hcp
(C)	NaCl crystal	(r)	Distance between closest particles is $\frac{\sqrt{3}}{4}$ a.
(D)	Diamond crystal	(s)	Only one type of voids are occupied

Exercise-2

> Marked questions are recommended for Revision.

PART - I : ONLY ONE OPTION CORRECT TYPE

1. Which of the following solids are not correctly matched with the bonds found between the constituent particles:

(A) Solid CO₂: Vanderwaal's

(C) Grey Cast Iron : Ionic

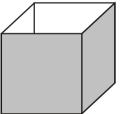
- (B) Graphite : Covalent and Vanderwaal
- (D) Metal alloys : lons-delocalised electrons

2.	(A) They possess high (B) All are electrolyte	is not correct for ionic on melting point and boiling		
		y of isomorphism properties of the bond	ng point	
3.24	An element (atomic m the element is (no. of a (A) 2.144 g/cm ³		ng bcc structure has unit (C) 7.289 g/cm ³	cell edge 400 pm. The density of (D) 10.376 g/cm ³
4.			. , _	rrangement (a = $2 \times \text{ radius of the}$
	particle).	Γ	4	
	(A) $\sqrt{\frac{8}{3}}$ a	(B) $\sqrt{\frac{4}{3}}$ a	(C) $\frac{1}{\sqrt{6}}$ a	(D) $\sqrt{\frac{2}{3}}$ a
5.2				Y atoms are at face centers.Then orner is replaced by Z atoms (also
	(A) $X_7Y_{24}Z_2$	(B) X ₇ Y ₂₄ Z	(C) X ₂₄ Y ₇ Z	(D) XY ₂₄ Z
6.		tical balls.What is the n is) that can be created?		are voids and triangular voids (in
	(A) 2, 4	(B) 4, 2	(C) 4, 3	(D) 3, 4
7.	In a simple cubic lattic the body centre is	ce of anions, the side le	ength of the unit cell is 2.	.88 Å. The diameter of the void in
	(A) 1.934 Å	(B) 0.461 Å	(C) 2.108 Å	(D) 4.988 Å
8.	In a multi layered close-packed structure (A) there are twice as many tetrahedral holes as many close-packed atoms (B) there are as many tetrahedral holes as many closed packed atoms (C) there are twice as many octahedral holes as many close-packed atoms (D) there are as many tetrahedral holes as many octahedral holes			
9.海	sixth of the tetrahedra compound is	I voids and cations B or	ccupy one-third of the oc	ngement. Cations A occupy one- tahedral voids. The formula of the
4.0	(A) A ₂ BO ₃	(B) AB ₂ O ₃	(C) $A_2B_2O_2$	(D) ABO ₃
10.	Platinum crystallizes i nearest neighbors is :	_	_	length 'a'. The distance between
	(A) a	(B) a √3 2	(C) a $\frac{\sqrt{2}}{2}$	(D) a $\frac{\sqrt{2}}{4}$
11.		um are respectively. [At 16 Å	crystal with a unit cell ler omic mass of Pt = 195] (B) 21.86 g. cm ⁻³ , 1.3 (D) None of these	ngth of 3.9231 Å. The density and
12.	between gold atoms is	S:	C C	length 4.070 Å. Closest distance
40	(A) 2.035 Å	(B) 8.140 Å	(C) 2.878 Å	(D) 1.357 Å
13.১	 Which of the following statements is correct in the rock-salt structure of ionic compounds? (A) Co-ordination number of cation is four whereas that of anion is six. (B) Co-ordination number of cation is six whereas that of anion is four. (C) Co-ordination number of each cation and anion is four. (D) Co-ordination number of each cation and anion is six. 			
14.		rystallizes in a cubic t crystal class does the (B) NaCl structure		and B atoms have coordination (D) Al ₂ O ₃ structure

Solid	State				
15.১	BaO has a rock-salt t number of Ba^{+2} ion to C (A) 4 : 8		ubjected to high pressu (C) 8 : 8	re, the ratio of the coordination (D) 4:4	
16.	exhibit		-	from the lattice point, is said to	
	(A) Surface defect	(B) Lattice defect	(C) Frenkel defect	(D) Schottky defect	
17.১	In the Schootky defect : (A) cations are missing from the lattice sites and occupy the interstitial sites (B) equal number of cations and anions are missing (C) anion are missing and electrons are present in their place (D) equal number of extra cations and electrons are present in the interstitial sites				
18.	NaCl shows Schottky defects and AgCl Frenkel defects. Their electrical conductivity is due to: (A) motion of ions and not the motion of electrons (B) motion of electrons and not the motion of ions (C) lower co-ordination number of NaCl (D) higher co-ordination number of AgCl				
19.	 Zinc Oxide, white in colour at room temperature, acquires yellow colour on heating due to: (A) Zn being a transition element. (B) paramagnetic nature of the compound. (C) trapping of electrons at the site vacated by Oxide ions. (D) Both (A) & (B). 				

PART - II : SINGLE AND DOUBLE VALUE INTEGER TYPE

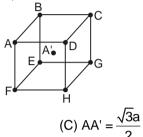
- How many of the following are Covalent network solids? S₈, Bronze, SiO₂, Diamond, ZnSO₄, Si, AlN, SiC, CO₂.
- 2. How many number of atom effectively present in a cubic unit formed by arrangement of eight B.C.C unit cell.
- **3.** How many spherical balls of radii 2 cm can be placed completely inside a cubical box of edge = 8 cm ?



- 4. What is the co-ordination number of an atom in its own layer in ABAB type arrangement.
- **5.** In ABAB arrangement if an atom is placed in A layer then calculate the number of atoms touching in its adjacent B layers ?
- 6. How many number octahedral voids are effectively inside an HCP unit cell.
- **7.** In a compound, oxide ions are arranged in cubic close packing arrangement. Cations A occupy onesixth of the tetrahedral voids and cations B occupy one-third of the octahedral voids. The formula of the compound is $A_xB_yO_z$, then find the value of x + y + z.
- **8.** The coordination number of cation and anion in Fluorite CaF_2 and Zinc blende ZnS are respectively x : y and a : b. Find (x + y + a + b).
- 9. In a crystalline solid having molecular formula A₂B anion (B) are arranged in cubic close packed lattice and cations (A) are equally distributed between octahedral and tetrahedral voids.
 (i) What percentage of octahedral voids is occupied?
 (ii) What percentage of tetrahedral voids is occupied?
 Report your answer ((i) (ii)).

PART - III : ONE OR MORE THAN ONE OPTIONS CORRECT TYPE

- **1.** Which of the following statements is/are false.
 - (A) It is the isotropic nature of amorphous solids that all the bonds are of equal strength.
 - (B) Entropy of a crystalline solid is higher than that of an amorphous solid.
 - (C) Amorphous solids have definite volume but not definite shape.
 - (D) Amorphous solids can become crystalline on slow heating (annealing).
- Amorphous solid can also be called _____.
 (A) pseudo solids
 (B) true solids
 (C) super cooled liquids
 (D) super cooled solids
- **3.** In body-centred cubic lattice given below, the three distance AB, AC and AA' are :



(A) AB = a (B) $AC = \sqrt{2}a$

- A metal crystallises in bcc. Find the % fraction of edge length not covered and also % fraction of edge length covered by atom is :
- (A) 10.4% (B) 13.4% (C) 86.6% (D) 11.4%
- 5. Select the correct statements about three dimensional HCP system.
 - (A) Number of atoms in HCP unit cell is six. (B) 1

(B) The volume of HCP unit cell is $24\sqrt{2}$ r³.

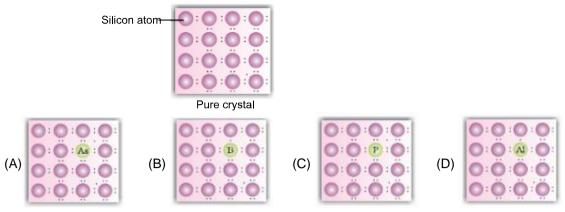
(D) $AA' = \sqrt{3}a$

- (C) The empty space in HCP unit cell is 26%. (D) The base area of HCP unit cell is $6\sqrt{3}$ r².
- 6. Which statements is/are true about HCP and CCP lattice
 - (A) Number of tetrahedral voids are twice of octahedral holes
 - (B) 12 tetrahedral and 6 octahedral voids are present in one HCP unit cell
 - (C) C.N. of HCP unit cell is 12
 - (D) If atom of tetrahedral voids displace into octahedral voids then it is Schootky defect.
- 7.aIn which of the following arrangements octahedral voids are formed?
(A) hcp(B) bcc(C) simple cubic(D) fcc
- 8. The number of tetrahedral voids per unit cell in NaCl crystal is _____.
 - (A) 4

4.

- (B) 8
- (C) twice the number of octahedral voids.
- (D) four times the number of octahedral voids.
- 9. Which of the following statements are correct :
 - (A) The coordination number of each type of ion in CsCl crystal is 8.
 - (B) A metal that crystallises in bcc structure has a coordination number of 12.
 - (C) A unit cell of ionic crystal shares some of its ion with other unit cells.
 - (D) The length of the unit cell in NaCl is 552 pm. (γ_{Na^+} = 95 pm, γ_{Cl^-} = 181 pm)
- **10.** Which of the following is/are correct ?
 - (A) Schottky defect lowers the density
 - (B) Frenkel defect increases the dielectric constant of the crystals
 - (C) Stoichiometric defects make the crystals electrical conductors
 - (D) In the Schoottky defect, equal number of extra cations and electrons are present in the interstitial sites

11. A perfect crystal of silicon (Fig) is doped with some elements as given in the options. Which of these options show n-type semiconductors?



12. Which of the following statements are true about semiconductors?

(A) Silicon doped with electron rich impurity is a p-type semiconductor.

(B) Silicon doped with an electron rich impurity is an n-type semiconductor.

(C) Delocalised electrons increase the conductivity of doped silicon.

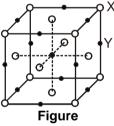
(D) An electron vacancy increases the conductivity of n-type semiconductor.

PART - IV : COMPREHENSION

Read the following comprehension carefully and answer the questions.

Comprehension #1

Consider the figure given for solid XY. Answer the following questions



1.2	The site Y represents (A) tetrahedral void	(B) Octahedral void	(C) triangular void	(D) cubical void.
2.24	The number of XY units (A) 4	s per unit cell is (B) 3	(C) 3	(D) 8
3.	Co-ordination number of (A) 3	of Y is (B) 4	(C) 6	(D) 8

Comprehension # 2

When an atom or an ion is missing from its normal lattice site, a lattice vacancy (Schottky defect) is created. In stoichiometric ionic crystals, a vacancy of one ion has to be accompanied by the vacancy of the oppositely charged ion in order to maintain electrical neutrality.

In a Frenkel defect an ion leaves its position in the lattice and occupies an interstitial void. This is the Frenkel defect commonly found along with the Schottky defects and interstitials. In pure alkali halides, Frenkel defects are not found since the ions cannot get into the interstitial sites. Frenkel defects are found in silver halides because of the small size of the Ag⁺ ion. Unlike Schottky defects, Frenkel defects do not change the density of the solids. In certain ionic solids (e.g. AgBr) both Schottky and Frenkel defects occur.

The defects discussed above do not disturb the stoichiometry of the crystalline material. There is large variety of non-stoichiometric inorganic solids which contain an excess or deficiency of one of the elements. Such solids showing deviations from the ideal stoichiometric composition form an important group of solids. For example in the vanadium oxide, VO_x, x can be anywhere between 0.6 and 1.3. There are solids which are difficult to prepare in the stoichiometric composition. Thus, the ideal composition in compounds such as FeO is difficult to obtain (normally we get a composition of Fe $_{0.95}$ O

but it may range from Fe0.93 O to Fe0.96O). Non-stoichiometric behaviour is most commonly found for transition metal compounds though is also known for some lanthanoids and actinoids. Zinc oxide loses oxygen reversibly at high temperatures and turns yellow in colour. The excess metal is accommodated interstitially, giving rise to electrons trapped in the neighbourhood. The enhanced electrical conductivity of the non-stoichiometric ZnO arises from these electrons. Anion vacancies in alkali halides are produced by heating the alkali halide crystals in an atmosphere of the alkali metal vapour. When the metal atoms deposit on the surface they diffuse into the crystal and after ionisation the alkali metal ion occupies cationic vacancy whereas electron occupies anionic vacancy. Electrons trapped in anion vacancies are referred to as F-centers (from Farbe the German word for colour) that gives rise to interesting colour in alkali halides. Thus, the excess of potassium in KCI makes the crystal appear violet and the excess of lithium in LiCI makes it pink. 4. When LiCI is heated into the vapour of lithium, the crystal acquires pink colour. This is due to (A) Schottkty defects (B) Frenkel defects (C) Metal excess defect leading to F-centers (D) Electronic defect Strongly heated ZnO crystal can conduct electricity. This is due to 5.2 (A) Movement of extra Zn²⁺ ions present in the interstitial sites (B) Movement of electrons in the anion vacancies (C) Movement of both Zn²⁺ ions and electrons (D) None of these AgCI is crystallized from molten AgCI containing a little CdCl₂. The solid obtained will have 6.2 (A) cationic vacancies equal to number of Cd²⁺ ions incorporated (B) cationic vacancies equal to double the number of Cd²⁺ ions (C) anionic vacancies (D) neither cationic nor anionic vacancies 7. Which of the following is most appropriate crystal to show Frenkel defect. (C) AgBr (A) CsCl (B) NaCl (D) $CaCl_2$ Comprehension # 3

Answer Question no. 8, 9 and 10 by appropriately matching the information given in the three columns of the following table. (Z = effective number of atoms)

Column 1	Column 2	Column 3
(I) Square 2D packing	(i) Z = 1 in smallest unit cell	(P) edge length = 2R in smallest unit cell
(II) Hexagonal 2D packing of circles	(ii) $Z \ge 3$ in smallest unit cell	(Q) close packing
(III) CCP	(iii) Coordination Number = 6	(R) packing efficiency > 50%
(IV) Simple cubic	(iv) Primitive unit cell	(S) can be made by 2D hexagonal layers
	possible	of spheres

8.^	Identify the true of	combination:		
	(A) (I) (i) P	(B) (II) (i) Q	(C) (III) (iii) R	(D) (IV) (ii) S
9.^		minimum void space the t		
	(A) (I) (i) P	(B) (II) (i) P	(C) (III) (iv) S	(D) (IV) (iii) R

10.^For the arrangement classified as ABAB type the correct combination is:
(A) (I) (ii) P(B) (III) (i) Q(C) (II) (iii) R(D) (IV) (iv) S

Exercise-3

* Marked Questions may have more than one correct option.

PART - I : JEE (ADVANCED) / IIT-JEE PROBLEMS (PREVIOUS YEARS)

1. In the figures given below show the location of atoms in three crystallographic planes in a fcc lattice. Draw the unit cell of the corresponding structure and identify these planes in your diagram.



 $(B) A_2B$





(D) A₃B₄

[JEE-2000, 3/100]

2. In a solid 'AB' having the NaCl structure, 'A' atoms occupy the corners of the cubic unit cell. If all the face centered atoms along one of the axes are removed, then the resultant stoichiometry of the solid is: [JEE-2001, 1/35]

(A) AB₂

A substance A_x B_y crystallizes in a face centered cubic lattice in which atoms 'A' occupy each corner of the cube and atoms 'B' occupy the centers of each face of the cube. Identify the correct composition of the substance A_x B_y. [JEE-2002, 3/90]

(C) A_4B_3

(A) AB₃ (C) A₃ B

the crystal.

3.

(B) A₄ B₃(D) composition cannot be specified

- 4. Marbles of diameter 10 mm each are to be arranged on a flat surface so that their centers lie within the area enclosed by four lines of length each 40 mm. Sketch the arrangement that will give the maximum number of marbles per unit area, that can be enclosed in this manner and deduce the expression to calculate it. [JEE-2003, 2/60]
- A binary salt AB (formula weight = 6.023 Y amu, where Y is an arbitrary number) has rock salt structure with 1 : 1 ratio of A to B. The shortest A—B distance in the unit cell is Y^{1/3} nm. [JEE-2004, 4/60] (a) Calculate the density of the salt in kg m⁻³.
 (b) Given that the measured density of the salt is 20 kg m⁻³, specify the type of point defect present in
- 6. In which of the following compounds the cations are present in alternate tetrahedral voids:

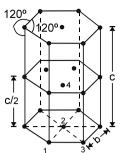
(A) NaCl (B) ZnS (C) CaF₂ (D) Na₂O

- 7. In a FCC lattice of a metal edge length is 400 pm. Find the maximum diameter of an atom which can be accommodated in an interstitial gap in this lattice without causing any distortion. [JEE-2005, 2/60]
- 8. For a unit cell edge length = 5Å, the element is of atomic mass 75, has density of 2gm/cc. Calculate atomic radius of the element. [JEE-2006, 6/184]
- 9. Match the crystal system/unit cells mentioned in Column I with their characteristic features mentioned in Column II. [JEE-2007, 6/162]

	Column I		Column II
(A)	simple cubic and face-centerd cubic	(p)	have these cell parameters $a=b=c$ and $\alpha=\beta=\gamma$
(B)	cubic and rhombohedral	(q)	are two crystal systems
(C)	cubic and tetragonal	(r)	have only two crystallographic angles of 90°
(D)	hexagonal and monoclinic	(S)	belong to same crystal system

Comprehension :

In hexagonal systems of crystals, a frequently encountered arrangement of atoms is described as a hexagonal prism. Here, the top and bottom of the cell are regular hexagons and three atoms are sandwiched in between them. A space-filling model of this structure, called hexagonal close-packed (HCP), is constituted of a sphere on a flat surface surrounded in the same plane by six identical spheres as closely as possible. There spheres are then placed over the first layer so that they touch each other and represent the second layer. Each one of these three spheres touches three spheres of the bottom layer. Finally, the second layer is covered with third layer that is identical to the bottom layer in relative position. Assume radius of every sphere to be 'r'.



- **10.** The number of atoms in the HCP unit cell is (A) 4 (B) 6
- **11.** The volume of this HCP unit cell is

(A) $24\sqrt{2} r^3$ (B) $16\sqrt{2} r^3$

12. The empty space in this HCP unit cell is (A) 74% (B) 47.6% (

(C) 32%

(C) $12\sqrt{2} r^3$

(C) 12

[JEE-2008, 4/163]

[JEE-2008, 4/163]

[JEE-2008, 4/163]

(D) 26%

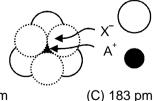
(D) 17

(D) $\frac{64}{3\sqrt{3}}r^3$

- 13.* The correct statement(s) regarding defects in solids is(are) : [JEE-2009, 4/160]
 (A) Frenkel defect is usually favoured by a very small difference in the sizes of cation and anion.
 (B) Frenkel defect is a dislocation defect.
 (C) Trapping of an electron in the lattice leads to the formation of F-center.
 - (D) Schottky defects have no effect on the physical properties of solids.
- 14. The packing efficiency of the two dimensional square unit cell shown below is : [JEE-2010, 5/163]
 - (A) 39.27%(B) 68.02%(C) 74.05%
 - (D) 78.54%
- 15. The number of hexagonal faces that are present in a truncated octahedron is
- 16. A compound $M_P X_q$ has cubic close packing (ccp) arrangement of X.

Its unit cell structure is shown below. The empirical formula of the compound is : [IIT-JEE-2012, 3/136]

- (A) MX
- (B) MX₂
- (C) M₂X
- (D) M₅X₁₄
- The arrangement of X⁻ ions around A⁺ ion in solid AX is given in the figure (not drawn to scale). If the radius of X⁻ is 250 pm, the radius of A⁺ is : [JEE(Advanced) 2013, 2/120]



(A) 104 pm

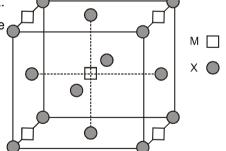
(B) 125 pm

(D) 57 pm

 \bigcirc



[JEE-2011, 3/160]



Solia	l State			_
<u>- 2011</u> 18.	If the unit cell of a m octahedral holes occ magnesium ions, m an	upied by aluminium io id n, respectively, are	ns and n fraction of	xygen atoms with m fraction of tetrahedral holes occupied by [JEE(Advanced) 2015, 4/168]
	(A) $\frac{1}{2}, \frac{1}{8}$	(B) 1, ¹ / ₄	(C) $\frac{1}{2}$, $\frac{1}{2}$	(D) $\frac{1}{4}$, $\frac{1}{8}$
19.*	The CORRECT statem	nent(s) for cubic close pa	cked (ccp) three dimension	ional structure is(are) [JEE(Advanced) 2016, 4/124]
	(B) The efficiency of at (C) The number of oct	om packing is 74%	resent in the topmost lay roids per atom are 1 and radius of the atom	ver is 12
20.		stance in the crystal is 8		re with a cell edge of 400 pm. If of atoms present in 256 g of the [JEE(Advanced) 2017, 2/122]
21.	constructed from the			structure (Z) whose unit cell is tions given below. Neglect the
	(ii) Replace all the face(iii) Remove all the cor(iv) Replace the central	I anion (X) with cation (N	v anions (X) I)	
	The value of $\left(\frac{\text{number}}{\text{number}}\right)$	r of anions) in Z is	[JI	EE(Advanced) 2018, 3/120]
	PART - II : JEE	(MAIN) / AIEEE F	PROBLEMS (PR	EVIOUS YEARS)
1.		in BCC and FCC type cr cell of their respective cr (2) 9 and 14		the number of atoms of Na and [AIEEE-2002, 3/225] (4) 2 and 4
2.	How many unit cells an [Atomic masses : Na = (1) 2.57 × 10 ²¹	23, Cl = 35.5]	oed ideal crystal of NaCl (3) 1.28 × 10 ²¹	[AIEEE-2003, 3/225]
3.	What type of crystal de Na ⁺ Cl ⁻ Cl ⁻ Na ⁺ Cl ⁻ Cl ⁻ Na ⁺ (1) Frenkel defect (3) interstitial defect	efect is indicated in the d Na ⁺ Cl ⁻ Na ⁺ Cl ⁻ Na ⁺ Cl ⁻ Na ⁺ Cl ⁻ Na ⁺	iagram below? Cl- Na ⁺ Cl- Na ⁺ (2) Schottky defect (4) Frenkel and Schottl	[AIEEE-2004, 3/225] ky defects
4.	•		of A ions at the corner formula for this compour	
	(1) AB	(2) A ₂ B	(3) AB ₃	[AIEEE-2005, 1½/225] (4) A ₃ B
5.	Total volume of atoms	present in a face-center	cubic unit cell of a metal	s (r is atomic radius). [AIEEE-2006, 3/165]
	(1) $\frac{20}{3}\pi r^3$	(2) $\frac{24}{3} \pi r^3$	(3) $\frac{12}{3} \pi r^3$	(4) $\frac{16}{3} \pi r^3$
6.	In a compound, atoms voids. The formula of t (1) X ₂ Y ₃	•	attice and those of eleme (3) X ₃ Y ₄	ent X occupy 2/3 rd of tetrahedral [AIEEE - 2008, 3/105] (4) X ₄ Y ₃
7.	Copper crystallises in t	fcc with a unit cell length	of 361 pm. What is the ra	adius of copper atom ? [AIEEE - 2009, 8/144]
	(1) 127 pm	(2) 157 pm	(3) 181 pm	(4) 108 pm

8.	The edge length of a f	ace centred cubic cell	of an ionic substance is	508 pm. If the radius of the cation
	is 110 pm, the radius o (1) 288 pm		(3) 618 pm	[AIEEE - 2010, 4/144] (4) 144 pm
9.	Percentages of free s respectively.	pace in cubic close pa	cked structure and in bo	ody centered packed structure are [AIEEE - 2010, 4/144]
	(1) 30% and 26%	(2) 26% and 32%	(3) 32% and 48%	
10.				ns and atom B occupies the factor centred points, the formula of the [AIEEE-2011, 4/120] (4) A ₂ B ₅
11.				
	Copper crystallises in		en edge of son pril. The f	adius of copper atom is: [AIEEE-2011, 4/120]
	(1) 108 pm	(2) 128 pm	(3) 157 pm	(4) 181 pm
12.	radius of the lithium wi	ll be :	-	of its unit cell is 351 pm. Atomic [AIEEE-2012, 4/120]
	(1) 75 pm	(2) 300 pm	(3) 240 pm	(4) 152 pm
13.	Experimentally it was its oxide. Fraction of th (1) 7.01%			Ietal M, present as M ²⁺ and M ³⁺ i [JEE(Main) 2013, 3/120) (4) 5.08%
14.		oody centred cubic la		ngth then which of the following [JEE(Main) 2014, 4/120]
	(1) $r_{Cs^+} + r_{Cl^-} = 3a$	(2) $r_{Cs^+} + r_{Cl^-} = \frac{3a}{2}$	(3) $r_{Cs^+} + r_{Cl^-} = \frac{\sqrt{3}}{2}a$	(4) $r_{CS^+} + r_{CI^-} = \sqrt{3}a$
15.	Sodium metal crystalli sodium atom is approx (1) 1.86Å		cubic lattice with a unit (3) 5.72Å	cell edge of 4.29Å. The radius o [JEE(Main) 2015, 4/120 (4) 0.93Å
16.	Which of the following (1) CrO2	compounds is metallic (2) VO ₂	and ferromagnetic ? (3) MnO ₂	[JEE(Main) 2016, 4/120 (4) TiO ₂
17.	A metal crystallises in approach between two			gth of its unit cell is 'a', the closes [JEE(Main) 2017, 4/120]
	(1) 2√2 a	(2) √2 a	(3) $\frac{a}{\sqrt{2}}$	(4) 2 ^a
18.	Which type of 'defect' ((1) Frenkel defect (3) Schottky defect	nas the presence of ca	tions in the interstitial site (2) Metal deficiency (4) Vacancy defect	, .
		ONLINI	E JEE-MAIN	
1.			ace centered points, the f	and atoms B at the face centered formula of the ionic compound is : in) 2014 Online (09-04-14), 4/120
	(1) AB ₂	(2) A ₅ B ₂	(3) A ₂ B ₃	(4) A_2B_5
2.	The appearance of co	our in solid alkali meta	I halides is generally due	
	(1) Schottky defect(3) Interstitial position			in) 2014 Online (11-04-14), 4/120
3.	In a monoclinic unit ce	Il the relation of sides a	and angles are respective	ely : n) 2014 Online (12-04-14), 4/120
	(1) a = b \neq c and α = β	$= \gamma = 90^{\circ}$	(2) a \neq b \neq c and α =	

Solid	State				
4.	The total number of o	ctahedral void (s) per ator	n present i		acked structure is : 14 Online (19-04-14), 4/120]
	(1) 2	(2) 4	(3) 1		4) 3
5.	Which of the follow antiferromagnetic sub		s the sch		nt of magnetic moments of 18 Online (15-04-18), 4/120]
	(1) (\uparrow) (\downarrow) (\downarrow)	() () () () () () () () () ()	(2) (1)	$(\uparrow) (\uparrow) (\uparrow)$	(10 cmme (10 cm + 10), 4/120)
		$\breve{\textcircled{0}}\breve{\textcircled{0}}\breve{\textcircled{0}}\breve{\textcircled{0}}$	(4)	$\textcircled{1}{1}$	$\widetilde{\bigcirc}$
6.	All of the following sha	are the same crystal struc	ture excep		40 Online (45 04 40) 4(400)
	(1) LiCl	(2) NaCl	(3) RbCl		18 Online (15-04-18), 4/120] 4) CsCl
7.	The one that is extens	sively used as a piezoelec	tric materi		10 Online (00-01-10) 1/120]
	(1) tridymite (3) quartz		(2) amor (4) mica	phous silica	19 Online (09-01-19), 4/120]
8.	At 100ºC, copper (Cu) has FCC unit cell structu	ure with ce	Il edge length of	x Å. What is the approximate
	density of Cu (in g cm	⁻³) at this temperature? [A	tomic mas		u] 19 Online (09-01-19), 4/120]
	(1) $\frac{205}{x^3}$	(2) $\frac{105}{x^3}$	(3) $\frac{422}{x^3}$		4) $\frac{211}{x^3}$
9.	Which premitive unit of	cell has unequal edge leng			l angles different from 90°?
	(1) Monoclinic	(2) Triclinic	(3) Hexa		Online (10-01-19), 4/120] 4) Tetragonal
10.		ula A ₂ B ₃ has the hcp lattic ccupied by the other atoms		atom forms the h	cp lattice and what fraction of
			I		Online (10-01-19), 4/120]
	(1) hcp lattice –A, $\frac{2}{3}$	Tetrahedral voids-B	(2) hcp lattice –B	$\frac{1}{3}$ Tetrahedral voids-A
	(3) hcp lattice –B, $\frac{2}{3}$	Fetrahedral voids-A	(4) hcp lattice –/	A, $\frac{1}{3}$ Tetrahedral voids-B
11.		y of 9 × 10 ³ kg m ⁻³ forms ss of the solid? [Avogadro	constant	≅ 6 × 10 ²³ mol ⁻¹ ,	
	(1) 0.0432 kg mol ⁻¹	(2) 0.0305 kg mol ⁻¹		- 、 /	9 Online (11-01-19), 4/120] 4) 0.0216 kg mol ⁻¹
12.		gest sphere which fits pro gth is represented by 'a')			edge of a body centred cubic
	(1) 0.047 a	(2) 0.027 a	(3) 0.134		9 Online (11-01-19), 4/120] 4) 0.067 a

Answers

EXERCISE - 1

PART - I

A-2.	Ques.	(a)	(b)	Total particles
	(i)	1/4	1	2
	(ii)	1/2	1/4	2
	(iii)	1/6	1/2	2
	(iv)	1/6	_	1/2
	(v)	1/3	1/6	1

<u>A-3.</u>

Crystal System	Features	Unit cell found	Examples
Monoclinic	a ≠ b ≠ c α = γ = 90°; β ≠ 120°, ≠ 90°, ≠ 60°	S, EC	Monoclinic sulphur, PbCrO ₄ , Na ₂ SO ₄ .10H ₂ O, Na ₂ B ₄ O ₇ .10H ₂ O.
Hexagonal	a = b ≠ c α = β = 90°, γ = 120°	S	Graphite, ZnO, CdS, Mg, PbI ₂ , SiC.
Triclinic	a ≠ b ≠ c α ≠ β ≠ γ ≠ 90°	S	K ₂ Cr ₂ O ₇ , CuSO ₄ .5H ₂ O, H ₃ BO ₃ .

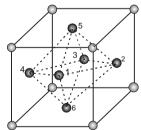
- **B-1.** Cube1 1/2 ; Cube2 1/4 ; Cube3 1 ; Cube4 1/8
- B-2. BCC

B-3. 124.27 pm, density = 7.30 g cm^{-3}

- C-1. ABC-ABC-Arrangement (CCP unit cell).
- **C-2.** $1.72 \times 10^{-23} \text{ cm}^3$, 1.60 Å

 $\textbf{C-3.} \hspace{0.5cm} (i) \hspace{0.5cm} b, \hspace{0.5cm} f, \hspace{0.5cm} g \hspace{0.5cm} are \hspace{0.5cm} identical; \hspace{0.5cm} c, \hspace{0.5cm} e \hspace{0.5cm} are \hspace{0.5cm} identical. \hspace{0.5cm} (ii) \hspace{0.5cm} d_a < [d_b = d_f = d_g] < [d_c = d_e] < d_d$

- **C-4.** (i) 2r, 2r, $2\sqrt{3}r$; (ii) Square, side = 2r.
- **C-5.** FCC, $\sqrt{2}$ Å
- **C-6.** ABAB.....type arrangement (unit cell = HCP).
- **D-1.** No, Rhombous: 2R, 60°, 120°; Triangular voids; 2 voids, 0.155 R.
- **D-2.** Octahedral void is present at the body center, which is formed by six face centered atoms and it consist at triangle faces.



- **D-3.** 12 and 6
- **D-4.** 4, 8, $\frac{a}{\sqrt{2}}$, $\frac{a}{2}$
- E-1. (a) CsCl type (b) ZnS type (c) NaCl type (d) CsCl type

In case of ZnS radius ratio is $\frac{r_{Zn^{2+}}}{r_{S^{2-}}} = 0.402.$ E-2.

That's why Zn²⁺ ion is present in tetrahedral void. If Zn²⁺ ion is present in octahedral void [For NaCl type structure] then anion-anion contact is there and compound become unstable. That's why. ZnS not crystallize in the NaCl structure.

- E-3. (i) Zn²⁺ ions occupy alternate Tetrahedral holes : (ii) Anti-Flourite: Anions in FCC and Cations in Tetrahedral holes, Fluorite: Cations in FCC and Anions in Tetrahedral holes
- (a) K^+ ion = 4 & Br^- ion = 4 (b) 6.56 Å (c) 2.80 g/cm³ (d) 0.414 E-4.
- F-1. Imperfections in solids : Any deviation from the perfectly ordered arrangement constitutes a defect or imperfection. These defect are sometimes called thermodynamic defects because the number of these defects depends on the temperature.

(i) Stoichiometric point defects : Schottky Defects. Interstitial Defects. Frenkel Defects.

(ii) Non-Stoichiometric defects : Metal excess defects, Metal deficiency defects.

- F-2. The reason of both is the presence of electron in anionic vacancies which is known as F- center.
- F-3. Silicon doped with phosphorus forms n - type of semiconductor. Phosphorus contains one extra electron than silicon which can move easily through the crystal and is responsible for semiconductor properties.
- F-4. In semiconductor fairly small band gap is present between valence band (filled with electrons) and conduction band (lowest unoccupied energy band). Increase in temperature gives thermal energy to some of the electrons and they move to conduction band and change the conductivity of semiconductor (Increase).

				PAR	RT - II				
A-1.	(C)	A-2.	(C)	A-3.	(D)	A-4.	(A)	A-5.	(A)
A-6.	(B)	B-1.	(A)	B-2.	(A)	B-3.	(B)	B-4.	(B)
B-5.	(A)	B-6.	(C)	C-1.	(C)	C-2.	(A)	C-3.	(A)
C-4.	(B)	C-5.	(C)	C-6.	(A)	C-7.	(C)	C-8.	(B)
C-9.	(A)	C-10.	(C)	C-11.	(C)	D-1.	(C)	D-2.	(A)
D-3.	(B)	D-4.	(C)	D-5.	(A)	D-6.	(A)	D-7.	(A)
E-1.	(C)	E-2.	(D)	E-3.	(C)	E-4.	(B)	E-5.	(B)
E-6.	(A)	E-7.	(A)	E-8.	(B)	F-1.	(C)	F-2.	(B)
F-3.	(A)	F-4.	(A)						

PART - III

(A - r,s); (B - r,s); (C - p); (D - q)

1.2

2.

			E	KER	CISE - 2				
				PA	RT - I				
1.	(C)	2.	(D)	3.	(B)	4.	(D)	5.	(B)
6.	(A)	7.	(C)	8.	(A)	9.	(D)	10.	(C)
11.	(B)	12.	(C)	13.	(D)	14.	(A)	15.	(C)
16.	(D)	17.	(B)	18.	(A)	19.	(C)		
				PA	RT - II				
1.	5	2.	16	3.	8	4.	6	5.	6
6.	6	7.	5 = (1 + 1 + 3)	8.	20=(8+4+4+4)	9.	50 = (100 - 50)	
				PA	RT - III				
1.	(ABC)	2.	(AC)	3.	(ABC)	4.	(BC)	5.	(ABCD)

6.	i <u>d State</u> (ABC)	7.	(AD)	8.	(BC)	9.	(ACD)	10.	(ABC)
11.	(AC)	12.	(BC)		()				· · ·
1.	(B)	2.	(A)	3.	RT - IV (C)	4.	(C)	5.	(B)
6.	(A)	7.	(C)	8.	(A)	9.	(B)	10.	(C)
			E	XER	CISE - 3				
					RT - I				
1.		•		2.	(D)	3.	(A)		
4.	25, 1.804 n	narbles/cm ²	2	5.	(a) 5 kg m⁻³,	(b) Canc	elled (Full ma	ırks given ir	ı part a)
	25, 1.804 m (B)	narbles/cm ² 7.	2 117.08 pm	5. 8.	(a) 5 kg m ⁻³ , 216.5 pm.		elled (Full ma - p,s); (B - q,	-	
6.					–			-	
6. 10.	(B)	7.	117.08 pm	8.	216.5 pm.	9. (A	- p,s); (B - q,	p); (C - q);	(D - q, r)
6. 10. 15.	(B) (B)	7. 11.	117.08 pm (A)	8. 12.	216.5 pm. (D)	9. (A 13.*	- p,s); (B - q, (BC)	p); (C - q); 14.	(D - q, r) (D)
6. 10. 15.	(B) (B) 8	7. 11. 16.	117.08 pm (A) (B)	8. 12. 17.	216.5 pm. (D)	9. (A 13.*	- p,s); (B - q, (BC)	p); (C - q); 14.	(D - q, r) (D)
6. 10. 15.	(B) (B) 8	7. 11. 16.	117.08 pm (A) (B) 3	8. 12. 17. PA	216.5 pm. (D) (A)	9. (A 13.*	- p,s); (B - q, (BC)	p); (C - q); 14.	(D - q, r) (D)
6. 10. 15. 20.	(B) (B) 8	7. 11. 16.	117.08 pm (A) (B) 3	8. 12. 17. PA	216.5 pm. (D) (A) RT - II	9. (A 13.*	- p,s); (B - q, (BC)	p); (C - q); 14.	(D - q, r) (D)
6. 10. 15. 20. 1.	(B) (B) 8 2	7. 11. 16. 21.	117.08 pm (A) (B) 3	8. 12. 17. PA FFLINE	216.5 pm. (D) (A) RT - II JEE-MAIN	9. (A 13.* 18.	- p,s); (B - q, (BC) (A)	p); (C - q); 14. 19.*	(D - q, r) (D) (BCD)
6. 10. 15. 20. 1. 6.	(B) (B) 8 2 (4)	7. 11. 16. 21. 2.	117.08 pm (A) (B) 3 O (1)	8. 12. 17. PA FFLINE 3.	216.5 pm. (D) (A) RT - II JEE-MAIN (2)	9. (A 13.* 18. 4.	- p,s); (B - q, (BC) (A) (3)	p); (C - q); 14. 19.* 5.	(D - q, r) (D) (BCD) (4)
6. 10. 15. 20. 1. 6. 11.	(B) (B) 8 2 (4) (4)	7. 11. 16. 21. 2. 7.	117.08 pm (A) (B) 3 O (1) (1)	8. 12. 17. PA FFLINE 3. 8.	216.5 pm. (D) (A) RT - II JEE-MAIN (2) (4)	9. (A 13.* 18. 4. 9.	- p,s); (B - q, (BC) (A) (3) (2)	p); (C - q); 14. 19.* 5. 10.	(D - q, r) (D) (BCD) (4) (4)
6. 10. 15. 20. 1. 6. 11.	(B) (B) 8 2 (4) (4) (4) (2)	7. 11. 16. 21. 2. 7. 12.	117.08 pm (A) (B) 3 O (1) (1) (1) (4) (3)	8. 12. 17. PA FFLINE 3. 8. 13. 18.	216.5 pm. (D) (A) RT - II JEE-MAIN (2) (4) (2)	9. (A 13.* 18. 4. 9.	- p,s); (B - q, (BC) (A) (3) (2)	p); (C - q); 14. 19.* 5. 10.	(D - q, r) (D) (BCD) (4) (4)
6. 10. 15. 20. 1. 6. 11. 16.	(B) (B) 8 2 (4) (4) (4) (2)	7. 11. 16. 21. 2. 7. 12.	117.08 pm (A) (B) 3 O (1) (1) (1) (4) (3)	8. 12. 17. PA FFLINE 3. 8. 13. 18.	216.5 pm. (D) (A) RT - II <u>JEE-MAIN</u> (2) (4) (2) (1)	9. (A 13.* 18. 4. 9.	- p,s); (B - q, (BC) (A) (3) (2)	p); (C - q); 14. 19.* 5. 10.	(D - q, r) (D) (BCD) (4) (4)
4. 6. 10. 15. 20. 1. 6. 11. 16. 1. 6.	(B) (B) 8 2 (4) (4) (4) (2) (1)	7. 11. 16. 21. 2. 7. 12. 17.	117.08 pm (A) (B) 3 (1) (1) (1) (4) (3) O	8. 12. 17. PA FFLINE 3. 8. 13. 13. 18. NLINE	216.5 pm. (D) (A) RT - II E JEE-MAIN (2) (4) (2) (1) JEE-MAIN	9. (A 13.* 18. 4. 9. 14.	- p,s); (B - q, (BC) (A) (3) (2) (3)	p); (C - q); 14. 19.* 5. 10. 15.	(D - q, r) (D) (BCD) (4) (4) (4) (1)